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High-efficiency orange and yellow organic light-emitting devices using platinum(II) complexes containing extended π-conjugated cyclometalated ligands as dopant materials

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Two luminescent platinum(II) complexes 1 and 2 containing extended π-conjugated cyclometalated ligands have been used as dopant materials for the construction of two high-efficiency organic light-emitting devices I and II. Device I (containing dopant 1), a maximum external quantum efficiency of $\eta_{\text{ext}}=12.4\%$, a maximum luminous efficiency of $32.3 \text{ cd/A}$, and a maximum power efficiency of $11.2 \text{ lm/W}$ were achieved at a current density of $J=3.1 \text{ mA/cm}^2$ (10 V), corresponding to a brightness of $1100 \text{ cd/m}^2$. The device exhibited a maximum brightness of $21700 \text{ cd/m}^2$ at 16 V and its Commission Internationale de L’Eclairage (CIE 1931) coordinates remained constant with increasing drive voltage. For device II (containing dopant 2), a maximum external quantum efficiency of $\eta_{\text{ext}}=16.1\%$, a maximum luminous efficiency of $\eta_{\text{l}}=51.8 \text{ cd/A}$, and a maximum power efficiency of $\eta_{\text{p}}=23.2 \text{ lm/W}$ were achieved at a current density of $J=0.44 \text{ mA/cm}^2$ (7 V), corresponding to a brightness of $230 \text{ cd/m}^2$. The device exhibited a maximum brightness of $23500 \text{ cd/m}^2$ at 16 V and nearly constant CIE coordinates ($x=0.44, y=0.54$).

To maximize the performance of electrophosphorescent devices, it is necessary to choose a suitable host material and a hole-and-exciton-blocking layer (HBL). We chose CBP as the host because the photoluminescence spectrum of CBP overlaps with the absorption spectra of the two Pt(II) complexes used as dopants in this work. Although such spectral overlap is relevant only to the transfer of singlet states, it may, nevertheless, provide a general indication of the probability for triplet transfer. Furthermore, we chose 2,9-dimethyl-4,7-diphenyl-1,10-phenanthroline (bathocuproine, BCP) for the HBL because of its deep highest occupied molecular orbital (HOMO) energy (6.5 eV), which can confine both holes and excitons within the emitting layer. The hole transporting layer (HTL) was $N,N’$-diphenyl-$N,N’$-bis(1-naphthyl)phenyl)-1,1’-biphenyl-4,4’-diamine (NPB) and the electron transporting layer (ETL) was BCP. The combined use of ETL and HBL eliminates the requirement for additional electron transporting material and simplifies the overall device architecture. Device architecture and

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The organic layers were deposited by thermal evaporation onto a cleaned glass substrate precoated with transparent, conductive indium tin oxide under a vacuum of 10−5 Torr. A 30-nm-thick film of NPB was first deposited as the HTL. A 20-nm-thick CBP host was then deposited, which was doped with 1–10 wt % of dopant 1 or 2. The doping level was controlled by varying the relative deposition rates for CBP and Pt(II) complexes. Next, a 40-nm-thick layer of BCP was deposited as the ETL and HBL. A shadow mask with a 3×3 mm² opening was used to define the cathode, which consisted of a 0.5-nm-thick layer of LiF with a 100-nm-thick aluminum cap. The electroluminescent (EL) spectra, brightness, and CIE coordinates (CIE 1931) of the OLEDs were measured with a Photo Research Inc. PR650 luminance meter. The luminance-current density–voltage characteristics were recorded simultaneously, with the EL spectra measured by combining a luminance meter with a Keithley model 2400 voltage-current source. All measurements were carried out at room temperature under ambient conditions.

To determine the optimal dopant concentration, OLEDs with different dopant concentrations were fabricated to examine the relationship between the luminous efficiency and the concentration of dopant used. For dopant 1, the optimal dopant concentration was around 5 wt %, at which value device I exhibited a maximal luminous efficiency of 32.3 cd/A. For dopant 2, the optimal doping level was 6 wt %, where device II showed a maximal luminous efficiency of 51.8 cd/A. Figure 2 shows the EL spectra for devices I and II at different applied voltages. Device I emitted bright orange light and the EL spectrum showed a peak maximum at 553 nm with a shoulder at λ = 594 nm. Its EL spectra and CIE coordinates are independent of current. When the applied voltage was increased from 4 to 18 V (corresponding to a current density of 0.076–388.9 mA/cm²), the CIE coordinates only changed from (0.461, 0.508) to (0.474, 0.507), indicating excellent color stability. Device II emitted yellow light and the EL spectrum had a major intensity peak at λmax = 540 nm, with another intensity peak at λ = 580 nm. Its EL spectra and CIE coordinates are also independent of current, only changing from (0.423, 0.546) to (0.440, 0.537) when the applied voltage was increased from 4 to 16 V.

Figure 3 shows the external quantum efficiency (ηext) and power efficiency (ηp) as a function of current density for devices I and II with optimized dopant concentration. For device I [with 5 wt % of dopant 1, as shown in Fig. 3(a)], the CIE coordinates of the spectra measured by combining a luminance meter with a Keithley model 2400 voltage-current source. All measurements were carried out at room temperature under ambient conditions.

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Figure 3 shows the external quantum efficiency (ηext) and power efficiency (ηp) as a function of current density for devices I and II with optimized dopant concentration. For device I [with 5 wt % of dopant 1, as shown in Fig. 3(a)], the external quantum efficiency (ηext) and power efficiency (ηp) were determined to be 12.4% and 11.2 lm/W, respectively, at a current density of J = 3.1 mA/cm² (10 V). The ηext increased with increasing current at small current density (J < 1 mA/cm²), Device I exhibited a gradual decrease of ηext with increasing current, which could be attributed to triplet-triplet annihilation. Even at a higher current density of J = 111 mA/cm² (15 V), the efficiency of device I remained high at ηext = 4.5% and ηp = 2.4 lm/W. For device II [with 6 wt % of dopant 2, as shown in Fig. 3(b)], maximum ηext = 16.1% and ηp = 23.2 lm/W were achieved at a current density of J = 0.44 mA/cm² (7 V), corresponding to a brightness of 230 cd/m². At the higher current density of J = 188.9 mA/cm² (15 V), the device efficiency remained high at ηext = 3.6%, ηL = 11.2 cd/A, and ηp = 2.3 lm/W. The luminous, quantum and power efficiencies of our OLEDs are superior to those of phosphor-sensitized fluorescent OLEDs.
and two or three times higher than that reported recently for Pt(II) complexes \cite{19}, and for iridium complexes \cite{20,21}. The reason why the external quantum efficiency of device I is significantly lower than that of device II may be due to the difference in emission quantum yield of the dopants. The emission quantum yield of dopant 1 in CH2Cl2 solution is 0.02, which is significantly lower than that of 0.68 of dopant 2 in the same solution.

Figure 4 shows the brightness–current density–applied voltage curves of devices I and II. For device I, the turn-on voltage of the device was ~4.5 V for a luminance of 1 cd/m2 and a maximum brightness of 21700 cd/m2 was achieved at a current density of J=326.6 mA/cm2 (17.5 V). The benchmark luminance of 100 cd/m2 was reached at a voltage of 7.4 V, corresponding to a current density of 0.19 mA/cm2. For device II, its turn-on voltage was ~4.2 V for 1 cd/m2 and a maximum brightness of 23500 cd/m2 was reached at a current density of J=222.2 mA/cm2 (15.5 V). The benchmark luminance of 100 cd/m2 was reached at a voltage of 6.4 V, corresponding to a current density of 0.31 mA/cm2. An interesting feature could be noted from Fig. 4, where device II shows higher current densities than device I at lower voltages. This is a reproducible finding even at the same dopant concentration. This implies that both charge injection and transport behavior for dopants 1 and 2 are different. The difference is tied to respective different HOMO and lowest unoccupied molecular orbital (LUMO) levels. In this work, the HOMO and LUMO energy levels of dopants 1 and 2 were estimated from their electrochemical data, which were measured by cyclic voltammetry (CV) using Ag/Ag+ electrode in 10−4 M DMF solution. The HOMO and LUMO levels of dopant 1 are 5.63 and 3.14 eV, and obtained 5.38 and 3.07 eV for dopant 2. The HOMO and LUMO levels of CBP are from Ref. 23, where they were determined by CV method to be 6.0 and 2.7 eV, respectively. Because the HOMO level of dopant 2 is 0.25 eV higher than that of dopant 1, the barrier to hole injection into dopant 2 from NPB is 0.25 eV lower than that to hole injection into dopant 1 from NPB; i.e., hole injection into dopant 2 from NPB is energetically more favorable than into dopant 1 at the same applied voltages. On the other hand, the LUMO level of dopant 1 is 0.07 eV lower than that of dopant 2. This means that the trap effect of dopant 1 is more effective than dopant 2 in trapping electrons. Once electrons are trapped, the mobility of electrons in CBP decreases, leading to the decline of the current density at the same voltages.

In summary, we have fabricated high-efficiency orange and yellow organic light-emitting devices using phosphorescent platinum(II) complexes as dopant materials. The use of [RC(N3)PtCl2] complexes provides an entry to a family of electrophosphorescent yellow emitters.

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FIG. 4. (Color online) Luminance–applied voltage–current density curves of device I (solid) and device II (open). Circles stand for current density and squares represent brightness.